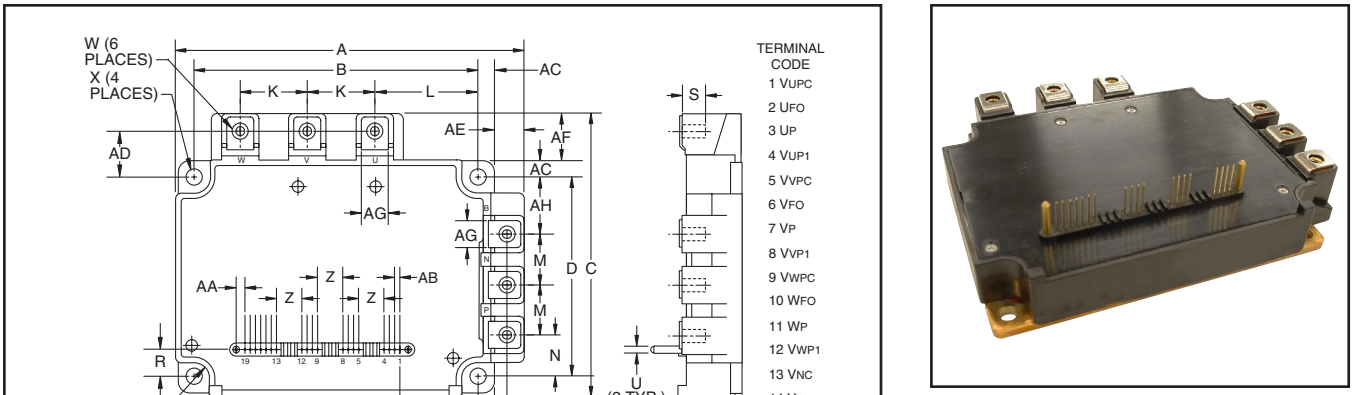
Powerex, Inc., 200 E. Hillis Street, Youngwood, Pennsylvania 15697-1800 (724) 925-7272

Intellimod™ L-Series

Three Phase
IGBT Inverter + Brake
200 Amperes/600 Volts



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	5.31	135.0
B	4.33±0.02	110±0.5
C	4.33	110.0
D	3.07	78.0±0.5
E	2.81	71.5
F	2.62	66.5
G	1.37	34.7
H	1.32	33.6
J	0.95+0.04/-0.01	24.1+1.0/-0.5
K	1.02	26.0
L	1.59	40.5
M	0.79	20.0
N	0.65	16.5
P	0.43±0.01	11.0±0.3
Q	1.19	30.15
R	0.43	11.0

Dimensions	Inches	Millimeters
S	0.51	13.0
T	0.16	4.0
U	0.1 Dia.	Dia.2.5
V	0.02 Sq.	Sq. 0.5
W	M5 Metric	M5
X	0.22 Dia.	Dia. 5.5
Y	0.24 Rad.	Rad. 6
Z	0.39	10.0
AA	0.13	3.25
AB	0.08	2.0
AC	0.24	6.05
AD	0.71	18.0
AE	0.46	11.7
AF	0.74	18.7
AG	0.41	10.5
AH	0.85	21.5

Description:
Powerex Intellimod™ Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:
- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
  - – Short Circuit
  - – Over Temperature Using On-chip Temperature Sensing
  - – Under Voltage
- ☐ Low Loss Using 5th Generation IGBT Chip

Applications:
- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:
Example: Select the complete part number from the table below -i.e. PM200RLA060 is a 600V, 200 Ampere Intellimod™ Intelligent Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 10)
PM	200	60

PM200RLA060
Intellimod™ L-Series
Three Phase IGBT Inverter + Brake
200 Amperes/600 Volts

Absolute Maximum Ratings, T_j = 25°C unless otherwise specified

Characteristics	Symbol	PM200RLA060	Units
Power Device Junction Temperature	T_j	-20 to 150	°C
Storage Temperature	T_{stg}	-40 to 125	°C
Module Case Operating Temperature (Note 1)	T_C	-20 to 100	°C
Mounting Torque, M5 Mounting Screws	—	31	in-lb
Mounting Torque, M5 Main Terminal Screws	—	31	in-lb
Module Weight (Typical)	—	800	Grams
Supply Voltage, Surge (Applied between P - N)	$V_{CC(surge)}$	550	Volts
Self-protection Supply Voltage Limit (Short Circuit protection Capability)*	$V_{CC(prot.)}$	400	Volts
Isolation Voltage, AC 1 minute, 60Hz Sinusoidal	V_{ISO}	2500	Volts

*V_D = 13.5 ~ 16.5V, Inverter Part, T_j = 125°C

IGBT Inverter Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current (T_C = 25°C)	$\pm I_C$	200	Amperes
Peak Collector Current (T_C = 25°C)	$\pm I_{CP}$	400	Amperes
Collector Dissipation, T_C = 25°C (Note 1)	P_C	595	Watts

IGBT Brake Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	600	Volts
Collector Current (T_C = 25°C)	$\pm I_C$	100	Amperes
Peak Collector Current (T_C = 25°C)	$\pm I_{CP}$	200	Amperes
Collector Dissipation, T_C = 25°C (Note 1)	P_C	357	Watts
Diode Rated DC Reverse Voltage (T_C = 25°C)	$V_{R(DC)}$	600	Volts
Diode Forward Current	I_F	100	Amperes

Control Sector

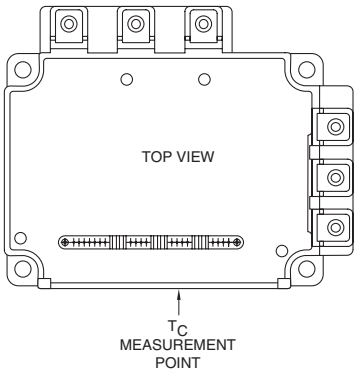
Supply Voltage (Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC})	V_D	20	Volts
Input Voltage (Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N- V_N- W_N-Br-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied between U_{FO}-V_{UPC}, V_{FO}-V_{VPC}, W_{FO}-V_{WPC}, F_O-V_{NC})	V_{FO}	20	Volts
Fault Output Current (U_{FO}, V_{FO}, W_{FO}, F_O Terminals)	I_{FO}	20	mA

PM200RLA060
Intellimod™ L-Series
Three Phase IGBT Inverter + Brake
200 Amperes/600 Volts

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, V_D = 15V, T_j = 25°C	—	—	1.0	mA
		$V_{CE} = V_{CES}$, V_D = 15V, T_j = 125°C	—	—	10	mA
Diode Forward Voltage	V_{EC}	$-I_C$ = 200A, V_{CIN} = 15V, V_D = 15V	—	2.2	3.3	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 200A, T_j = 25°C	—	1.6	2.1	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 200A, T_j = 125°C	—	1.5	2.0	Volts
Inductive Load Switching Times	t_{on}	V_D = 15V, V_{CIN} = 0 ⇔ 15V, V_{CC} = 300V, I_C = 200A, T_j = 125°C	0.5	1.0	2.4	µs
	t_{rr}		—	0.2	0.4	µs
	$t_{C(on)}$		—	0.4	1.0	µs
	t_{off}		—	1.2	2.5	µs
	$t_{C(off)}$		—	0.5	1.0	µs
IGBT Brake Sector						
Collector-Emitter Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, V_D = 15V, T_j = 25°C	—	—	1.0	mA
		$V_{CE} = V_{CES}$, V_D = 15V, T_j = 125°C	—	—	10	mA
Diode Forward Voltage	V_{FM}	I_F = 100A	—	2.2	3.3	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 100A, T_j = 25°C	—	1.6	2.1	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 100A, T_j = 125°C	—	1.5	2.0	Volts

Note 1: T_C Baseplate Measurement Point



Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Short Circuit Trip Level	SC	Inverter Part	400	—	—	Amperes
(-20°C ≤ T_j ≤ 125°C, V_D = 15V)		Brake Part	200	—	—	Amperes
Short Circuit Current Delay Time	$t_{off(SC)}$	V_D = 15V	—	0.2	—	µs
Over Temperature Protection	OT	Trip Level	135	145	155	°C
(Detect T_j of IGBT Chip)	OT_R	Reset Level	—	125	—	°C
Supply Circuit Under-voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
(-20 ≤ T_j ≤ 125°C)	UV_R	Reset Level	—	12.5	—	Volts
Circuit Current	I_D	V_D = 15V, V_{CIN} = 15V, V_{N1}-V_{NC}	—	24	34	mA
		V_D = 15V, V_{CIN} = 15V, V_{XP1}-V_{XPC}	—	6	12	mA
Input ON Threshold Voltage	$V_{th(on)}$	Applied between U_P-V_{UPC},	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{th(off)}$	V_P-V_{VPC}, W_P-V_{WPC}, U_N- V_N- W_N-Br-V_{NC}	1.7	2.0	2.3	Volts
Fault Output Current*	$I_{FO(H)}$	V_D = 15V, V_{CIN} = 15V	—	—	0.01	mA
	$I_{FO(L)}$	V_D = 15V, V_{CIN} = 15V	—	10	15	mA
Fault Output Pulse Width*	t_{FO}	V_D = 15V	1.0	1.8	—	ms

*Fault output is given only when the internal SC, OT and UV protections schemes of either upper or lower devide operate to protect it.

Thermal Characteristics, T_j = 25°C unless otherwise specified

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Inverter IGBT (Per 1/6 Module) (Note 1)	—	—	0.21	°C/Watt
	$R_{th(j-c)D}$	Inverter FWDi (Per 1/6 Module)(Note 1)	—	—	0.31	°C/Watt
	$R_{th(j-c)Q}$	Brake IGBT (Per 1/6 Module) (Note 1)	—	—	0.35	°C/Watt
	$R_{th(j-c)D}$	Brake FWDi (Per 1/6 Module)(Note 1)	—	—	0.56	°C/Watt
	$R_{th(j-c)Q}$	Inverter IGBT (Per 1/6 Module) (Note 2)	—	—	0.16**	°C/Watt
	$R_{th(j-c)D}$	Inverter FWDi (Per 1/6 Module)(Note 2)	—	—	0.24**	°C/Watt
	$R_{th(j-c)Q}$	Brake IGBT (Per 1/6 Module) (Note 2)	—	—	0.27**	°C/Watt
	$R_{th(j-c)D}$	Brake FWDi (Per 1/6 Module)(Note 2)	—	—	0.43**	°C/Watt
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.023	°C/Watt

** If you use this value, $R_{th(f-a)}$ should be measured just under the chips.
Note 2: T_C measurement point is just under the chip.

Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	≤400	Volts
Control Supply Voltage***	V_D	Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC}	15.0 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P-V_{UPC},	≤0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$	V_P-V_{VPC}, W_P-V_{WPC}, U_N- V_N- W_N-Br-V_{NC}	≥9.0	Volts
PWM Input Frequency	f_{PWM}		≤20	kHz
Arm Shoot-through Blocking Time	t_{DEAD}	Input Signal	≥2.0	µs

*** With ripple satisfying the following conditions: dv/dt swing ≤ ±5V/µs, Variation ≤ 2V peak to peak.